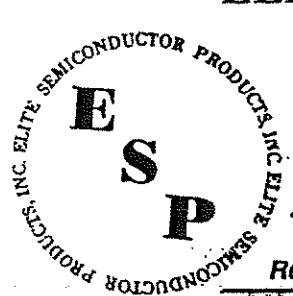


ELITE SEMICONDUCTOR PRODUCTS, INC.

860 North Richmond Ave. Lindenhurst, New York 11757
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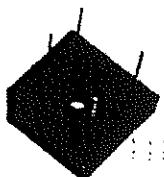


GBPC12, 15, 25 AND 35 SERIES

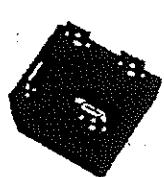
GLASS PASSIVATED SINGLE-PHASE BRIDGE RECTIFIER

Reverse Voltage - 50 to 1000 Volts Current Voltage - 12.0 to 35.0 Amperes

GBPC - W Wire leads



GBPC - Standard



FEATURES

- ♦ The plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ♦ This series is UL recognized under component index, file number E304417
- ♦ Integrally molded heatsink provides very low thermal resistance for maximum heat dissipation
- ♦ Universal 3-way terminals; snap-on, wire wrap-around, or P.C.B. mounting
- ♦ High forward surge current capabilities
- ♦ Glass passivated chip junctions
- ♦ Typical IR less than $0.3\mu A$
- ♦ High temperature soldering guaranteed:
 $260^{\circ}C/10$ seconds at 5lbs. (2.3 kg) tension

MECHANICAL DATA

Case: Molded plastic with heatsink integrally mounted in the bridge encapsulation

Terminals: Either plated 0.25" (6.35mm). Faston lugs or plated copper leads 0.040" (1.02mm) diameter. Suffix letter "W" added to indicate leads (e.g. GBPC12005W).

Mounting Position: See NOTE 3

Polarity: Polarity symbols molded on body

Mounting Torque: 20 in. - lb. max. **Weight:** 0.53 ounce, 15 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at $25^{\circ}C$ ambient temperature unless otherwise specified.

		SYMBOLS	005	01	02	04	06	08	10	UNITS
Maximum repetitive peak reverse voltage.	V _{RRM}		50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}		35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}		50	100	200	400	600	800	1000	Volts
Maximum average forward rectified output current (SEE FIG.1)	GBPC12 GBPC15 GBPC25 GBPC35	I _{AV}					12.0	15.0	25.0	Amps
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	GBPC12 GBPC15 GBPC25 GBPC35	I _{FSM}				200.0	300.0	300.0	400.0	Amps
Rating (non-repetitive, for t greater than 1ms and less than 8.3ms) for fusing	GBPC12 GBPC15 GBPC25 GBPC35	P _I				160.0	375.0	375.0	660.0	A ² sec
Maximum instantaneous forward voltage drop per leg at	GBPC12 GBPC15 GBPC25 GBPC35	I _F =6.0A I _F =7.5A I _F =12.5A I _F =17.5A	V _F				1.1			Volts
Maximum reverse DC current at rated DC blocking voltage per leg	T _A =25°C T _A =125°C	I _R				5.0	500.0			μA
RMS isolation voltage from case to leads	V _{iso}					2500.0				Volts
Typical junction capacitance per leg (NOTE 1)	C _J					300.0				pF
Typical thermal resistance per leg (NOTE 2)	GBPC12-25 GBPC35	R _{thJC}				1.9	1.4			°C/W
Operating junction storage temperature range	T _J , T _{STG}					-55 to +150				°C

NOTES:

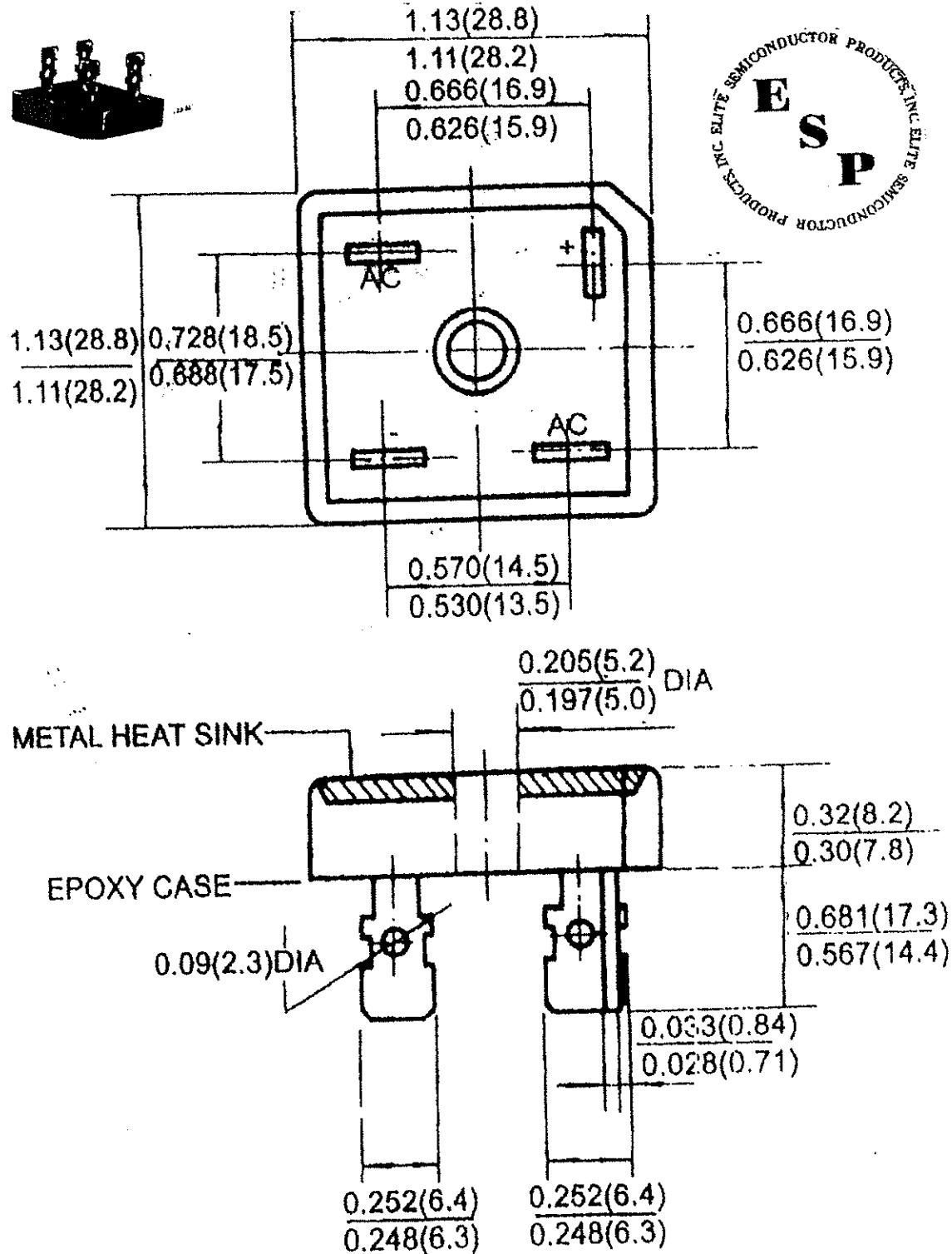
(1) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(2) Thermal resistance from junction to case per leg

(3) Bolt down on heat-sink with silicone thermal compound between bridge and mounting surface for maximum heat transfer efficiency with #10 screw

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